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November 2016

ON Semiconductor® FFSP15120A

Silicon Carbide Schottky Diode 1200 V, 15 A

Features

- Max Junction Temperature 175 °C
- · Avalanche Rated 145 mJ
- · High Surge Current Capacity
- · Positive Temperature Coefficient
- · Ease of Paralleling
- No Reverse Recovery / No Forward Recovery

Applications

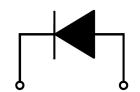
- · General Purpose
- · SMPS, Solar Inverter, UPS
- · Power Switching Circuits

Description

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size & cost.



1. Cathode 2. Anode



1. Cathode 2. Anode

Absolute Maximum Ratings T_C = 25 °C unless otherwise noted.

Symbol	Parameter		FFSP15120A	Unit
V_{RRM}	Peak Repetitive Reverse Voltage		1200	V
E _{AS}	Single Pulse Avalanche Energy (Note 1)		145	mJ
I _F	Continuous Rectified Forward Current @ Tc < 148 °C		15	Α
I _{F, Max}	Non-Repetitive Peak Forward Surge Current	T _C = 25 °C, 10 μs	920	Α
		T _C = 150 °C, 10 μs	870	Α
I _{F,SM}	Non-Repetitive Forward Surge Current	Half-Sine Pulse, t _p = 8.3 ms	115	Α
I _{F,RM}	Repetitive Forward Surge Current	Half-Sine Pulse, t _p = 8.3 ms	50	Α
Ptot	Davisa Dissination	T _C = 25 °C	300	W
	Power Dissipation	T _C = 150 °C	50	W
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +175	°C

Thermal Characteristic

Symbol	Parameter	FFSP15120A	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max	0.5	°C/W

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFSP15120A	FFSP15120A	TO-220-2L	Tube	N/A	N/A	50 units

Electrical Characteristics $T_C = 25$ °C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _F	Forward Voltage	I _F = 15 A, T _C = 25 °C	-	1.45	1.75	V
		$I_F = 15 \text{ A}, T_C = 125 ^{\circ}\text{C}$	-	1.7	2	
		$I_F = 15 \text{ A}, T_C = 175 ^{\circ}\text{C}$	-	2	2.4	
I _R	Reverse Current	V _R = 1200 V, T _C = 25 °C	-	-	200	μА
		$V_R = 1200 \text{ V}, T_C = 125 ^{\circ}\text{C}$	-	-	300	
		$V_R = 1200 \text{ V}, T_C = 175 ^{\circ}\text{C}$	-	-	400	
Q_C	Total Capacitive Charge	V = 800 V	-	95	-	nC
С	Total Capacitance	V _R = 1 V, f = 100 kHz	-	936	-	pF
		$V_R = 400 \text{ V}, f = 100 \text{ kHz}$	-	86	-	
		$V_R = 800 \text{ V}, f = 100 \text{ kHz}$	-	68	-	

Typical Characteristics $T_J = 25$ °C unless otherwise noted.

Figure 1. Forward Characteristics

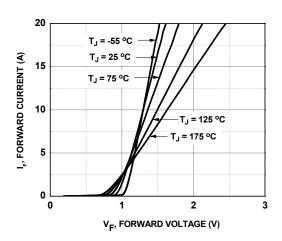


Figure 3. Reverse Characteristics

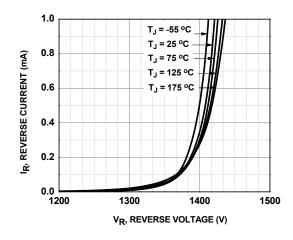


Figure 2. Reverse Characteristics

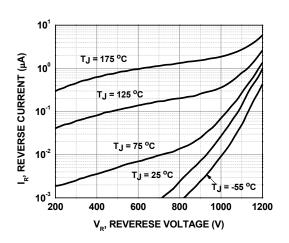
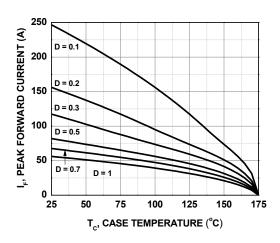


Figure 4. Current Derating



Notes: 1: EAS of 145 mJ is based on starting T_J = 25 °C, L = 0.5 mH, I_{AS} = 24 A, V = 150 V.

Typical Characteristics T_J = 25 °C unless otherwise noted.

Figure 5. Power Derating

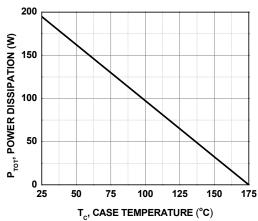


Figure 7. Capacitance vs. Reverse Voltage

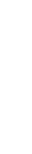


Figure 6. Capacitive Charge vs. Reverse Voltage

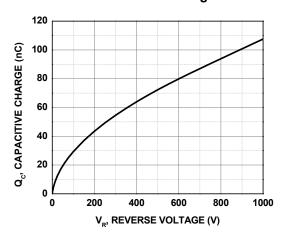
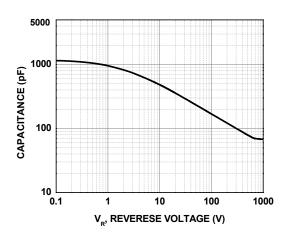


Figure 8. Capacitance Stored Energy



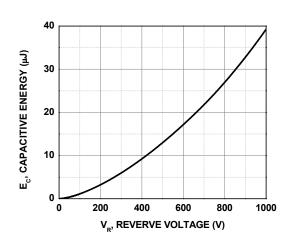
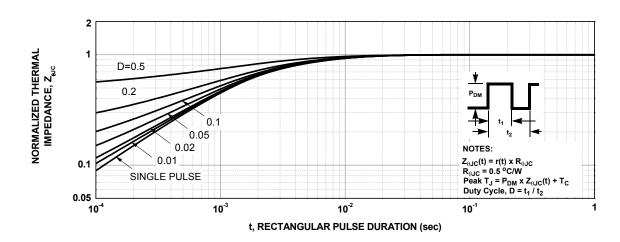
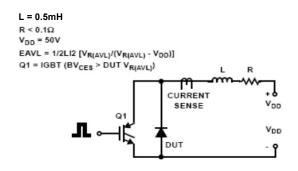


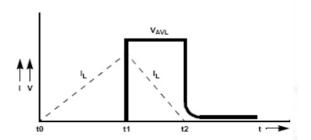
Figure 9. Junction-to-Case Transient Thermal Response Curve



Test Circuit and Waveforms

Figure 10. Unclamped Inductive Switching Test Circuit & Waveform





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